



MJD32C

100V PNP HIGH VOLTAGE TRANSISTOR IN TO252

Features

- $BV_{CEO} > -100V$
- I_C = -3A high Continuous Collector Current
- I_{CM} = -5A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Complementary NPN Type: MJD31C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

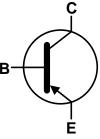
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.34 grams (Approximate)

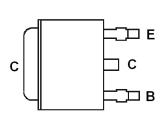




Top View







Pin Out Configuration Top View

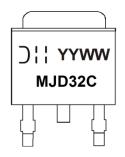
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MJD32C-13	AEC-Q101	MJD32C	13	16	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green"
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



MJD32C = Product Type Marking Code I = Manufacturers' code marking YYWW = Date Code Marking YY = Last Digit of Year (ex: 17 = 2017) WW = Week Code (01 - 53)

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-100	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-100	V
Emitter-Base Voltage	V_{EBO}	-6	V
Continuous Collector Current	lc	-3	A
Peak Pulse Collector Current	I _{CM}	-5	А
Continuous Base Current	I _B	-1	A
Power Dissipation	P _D	15	W

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.9		
Power Dissipation	(Note 6)	P_D	2.1	W	
	(Note 7)		1.6		
	(Note 5)		32		
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	59	0000	
	(Note 7)		80	°C/W	
Thermal Resistance, Junction to Leads (Note		$R_{ heta JL}$	3.6		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

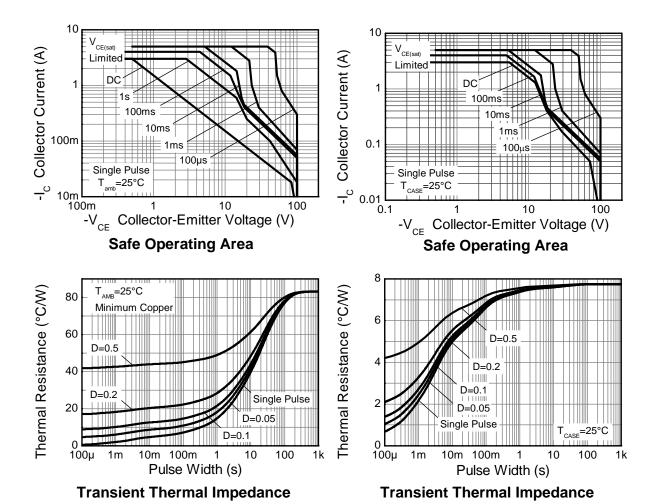
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 5. For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured For a device mounted with the exposed collector pad on summ x summ x 202 copperunder still air conditions whilst operating in a steady-state.
 Same as note (5), except mounted on 25mm x 25mm 1oz copper.
 Same as note (5), except mounted on minimum recommended pad (MRP) layout.
 Thermal resistance from junction to solder-point (on the exposed collector pad).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	-100	_	_	V	$I_C = -30 \text{mA}, I_B = 0$
Collector Cut-off Current	I _{CEO}	1	_	-1	μΑ	$V_{CB} = -60V, I_B = 0$
Collector Cut-off Current	I _{CES}	_	_	-1	μΑ	$V_{CE} = -100V, V_{EB} = 0$
Emitter Cut-off Current	I _{EBO}	_	_	-1	μΑ	$V_{EB} = -5V, I_{C} = 0$
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	_	_	-1.2	V	$I_C = -3.0A$, $I_B = -375mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	_	-1.8	V	$I_C = -3A$, $V_{CE} = -4V$
DC Current Gain (Note 10)	h	25		_		V _{CE} = -4V, I _C = -1A
De current Gain (Note 10)	h _{FE}	10	_	50		$V_{CE} = -4V, I_{C} = -3A$
Current Signal Current Gain	H _{fe}	20	_			$V_{CE} = -10V$, $I_{C} = -0.5A$, $f = 1KHz$
Current Gain-Bandwidth Product	f _T	3.0	_	_	MHz	I _C = -500mA, V _{CE} = -10V, f = 1MHz

Note: 10. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

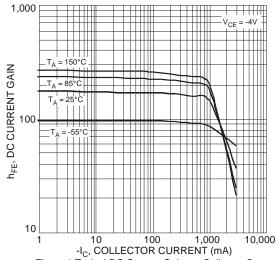


Figure 1 Typical DC Current Gain vs. Collector Current

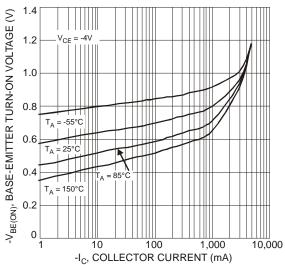


Figure 3 Typical Base-Emitter Turn-On Voltage
vs. Collector Current

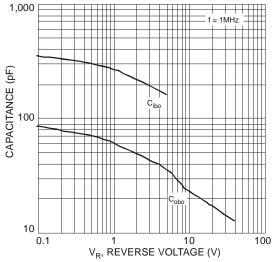


Figure 5 Typical Capacitance Characteristics

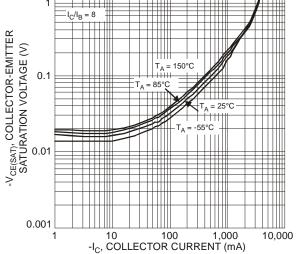


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

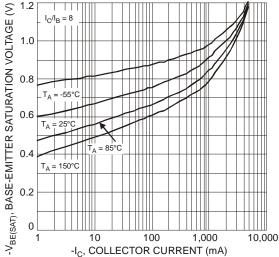
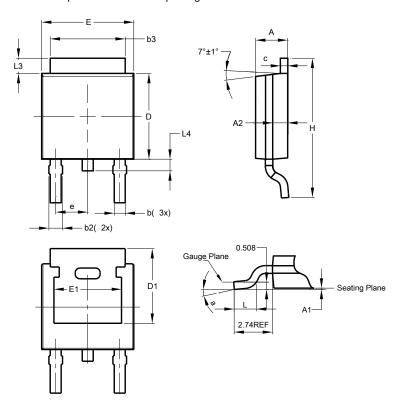


Figure 4 Typical Base-Emitter Saturation Voltage vs. Collector Current



Package Outline Dimensions

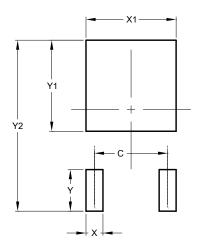
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)				
Dim	Min	Max	Тур	
Α	2.19	2.39	2.29	
A1	0.00	0.13	0.08	
A2	0.97	1.17	1.07	
b	0.64	0.88	0.783	
b2	0.76	1.14	0.95	
b3	5.21	5.46	5.33	
C	0.45	0.58	0.531	
D	6.00	6.20	6.10	
D1	5.21	-	-	
е	-	-	2.286	
Е	6.45	6.70	6.58	
E1	4.32	-	-	
Н	9.40	10.41	9.91	
L	1.40	1.78	1.59	
L3	0.88	1.27	1.08	
L4	0.64	1.02	0.83	
а	0°	10°	-	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	4.572
Χ	1.060
X1	5.632
Υ	2.600
Y1	5.700
Y2	10.700

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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